## **Refine Search**

#### Search Results -

Terms	Documents
L2 and L24	7

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Set Nam- side by sid		Hit Count S	Set Name result set
DB=P	GPB, USPT, EPAB, JPAB, DWPI, TDBD; PLUR = YES;	OP = OR	
<u>L27</u>	12 and 124	7	<u>L27</u>
<u>L26</u>	12 and L25	0	<u>L26</u>
<u>L25</u>	110 and L24	0	<u>L25</u>
<u>L24</u>	13 and 16 and 123	155	<u>L24</u>
<u>L23</u>	(116 or 117 or 118 or 119 or 120 or 121 or 122)	1964	<u>L23</u>
<u>L22</u>	MATSUBARA-KEN\$.in.	843	<u>L22</u>
<u>L21</u>	FUJISAWA-TOMOYUKI\$.in.	42	<u>L21</u>
<u>L20</u>	TAMURA-TAKAYUKI\$.in.	277	<u>L20</u>
<u>L19</u>	NOZOE-ATSUSHI\$.in.	100	<u>L19</u>
<u>L18</u>	HORII-TAKASHI\$.in.	166	<u>L18</u>
<u>L17</u>	YOSHIDA-KEIICHi\$.in.	610	<u>L17</u>
<u>L16</u>	TAKASE-YOSHINORI\$.in.	33	<u>L16</u>
<u>L15</u>	12 and L14	0	<u>L15</u>
<u>L14</u>	110 and L13	19	<u>L14</u>

initializ\$ near3 13	4675	<u>L13</u>
17 and 18	2	<u>L12</u>
17 and 18 and L10	0	<u>L11</u>
l3 near3 L9	247	<u>L10</u>
(outside or external) near2 access	33297	<u>L9</u>
16 near2 14 near3 15	252	<u>L8</u>
13 near2 14 near3 15	645	<u>L7</u>
(nonvolatile or (non-volatile) or flash) adj2 memory	245789	<u>L6</u>
area or region	5146770	<u>L5</u>
divid\$	1931955	<u>L4</u>
buffer	904402	<u>L3</u>
711/103.ccls.	2009	<u>L2</u>
510150.ap.	8	<u>L1</u>
	13 near3 L9 (outside or external) near2 access 16 near2 14 near3 15 13 near2 14 near3 15 (nonvolatile or (non-volatile) or flash) adj2 memory area or region divid\$ buffer 711/103.ccls.	17 and 18       2         17 and 18 and L10       0         13 near3 L9       247         (outside or external) near2 access       33297         16 near2 14 near3 15       252         13 near2 14 near3 15       645         (nonvolatile or (non-volatile) or flash) adj2 memory       245789         area or region       5146770         divid\$       1931955         buffer       904402         711/103.ccls.       2009

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### **Refine Search**

#### Search Results -

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Search:

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et Name		Hit Count	Set Name result set
DB=PC	GPB, USPT, EPAB, JPAB, DWPI, TDBD; PLUR=YES;	OP = OR	
<u>L15</u>	12 and L14	0	<u>L15</u>
<u>L14</u>	110 and L13	19	<u>L14</u>
<u>L13</u>	initializ\$ near3 13	4675	<u>L13</u>
<u>L12</u>	17-and 18	2	<u>L12</u>
<u>L11</u>	17 and 18 and L10	0	<u>L11</u>
<u>L10</u>	13 near3 L9	247	<u>L10</u>
<u>L9</u>	(outside or external) near2 access	33297	<u>L9</u>
<u>L8</u>	16 near2 14 near3 15	252	<u>L8</u>
<u>L7</u>	13 near2 14 near3 15	645	<u>L7</u>
<u>L6</u>	(nonvolatile or (non-volatile) or flash) adj2 memory	245789	<u>L6</u>
<u>L5</u>	area or region	5146770	<u>L5</u>
<u>L4</u>	divid\$	1931955	<u>L4</u>
<u>L3</u>	buffer	904402	<u>L3</u>
<u>L2</u>	711/103.ccls.	2009	<u>L2</u>

<u>L1</u>. 5101,50.ap.

8 <u>L1</u>

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	Term:			
	Display: 20 Docum	ients in <u>Display Fo</u>	rmat: - S	tarting with Number
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<u>L9</u>	17 and L8		39	<u>L9</u>
<u>L8</u>	13 near3 15		5216	<u>L8</u>
<u>L7</u>	12 and 16		113	<u>L7</u>
<u>L6</u>	13 near3 14		994	<u>L6</u>
<u>L5</u>	buffer or cache		976664	<u>L5</u>
<u>L4</u>	bank		253258	<u>L4</u>
<u>L3</u>	(nonvolatile or non-volatile	or flash) adj2 memo	•	<u>L3</u>
<u>L2</u>	711/103.ccls.		2009	<u>L2</u>
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- Run a search

Sear	ch Query Display	
Rece	ent Search Queries	Results
<u>#1</u>	((nonvolatile <or> flash <and> memory)<in>metadata)</in></and></or>	2770
<u>#2</u>	(((((nonvolatile <or> flash <and> memory)<in>metadata))<and> (buffer<in>metadata))</in></and></in></and></or>	59
<u>#3</u>	(((((((nonvolatile <or> flash <and> memory)<in>metadata))<and> (buffer<in>metadata)))<and>((outside or independent) <and> access*<in>metadata))</in></and></and></in></and></in></and></or>	4

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